

2026/2027 MPW schedule

Last updated: October 20, 2026

MPW name	Fab	Processes	Tape-In	Ship Date
CA18 - B6407	NPB - Fab 3	RFCMOS 0.18um	4-28-26	11-05-26
PH18M* - B6408	NPB - Fab 3	SiPho 0.18um	5-12-26	1-04-27
SB*18 - B6412	NPB - Fab 3	SiGe BiCMOS 0.18um	7-14-26	2-01-27
CA18 - B6413	NPB - Fab 3	RFCMOS 0.18um	7-28-26	1-08-27
PH18M* - B6414	NPB - Fab 3	SiPho 0.18um	8-11-26	04-05-27
38th MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	8-24-26	**
SB*18 - B6415	NPB - Fab 3	SiGe BiCMOS 0.18um	8-25-26	3-04-27
2nd MPW RFSOI-RSS6T	TSIT - Fab 10	90RSC/65RSA2/65RSB2/65RSC	9-10-26	**
SBC18HE5PCA - B6416	NPB - Fab 3	SiGe BiCMOS 0.18um with PCM RF Switch	9-15-26	**
40th MPW - Uozu, Japan	TPSCo - Fab 7	CMOS, PM, RFCMOS & SiGe, 65nm : TPS65SLA/SLC, TPS65PMA/PMB/PMC/PMD/PMK/PML/MSA/MSB/MSB/MSD/MSK/MSL, TPS65RF, TPS65SG	9-28-26	**
SB*18 - B6417	NPB - Fab 3	SiGe BiCMOS 0.18um	10-6-26	4-15-27
41th MPW - Uozu, Japan	TPSCo - Fab 7	300mm Silicon Photonics: TPS45PHD	10-26-26	**
PH18M* - B6418	NPB - Fab 3	SiPho 0.18um	10-27-26	6-21-27
SH226T18NOV	MH - Fab 2	CIS 0.18u Image Sensor CMOS+ 0.16u, 0.18u RF, RFID, PM	11-10-26 11-17-26	**
39th MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	11-24-26	**
SB*18 - B6700	NPB - Fab 3	SiGe BiCMOS 0.18um	1-19-27	7-29-27
CA18 - B6701	NPB - Fab 3	RFCMOS 0.18um	2-02-27	7-16-27
PH18M* - B6702	NPB - Fab 3	SiPho 0.18um	2-16-27	10-11-27
40th MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	2-24-27	**
SB*18 - B6703	NPB - Fab 3	SiGe BiCMOS 0.18um	3-02-27	9-09-27
PH18DA - B6704	NPB - Fab 3	SiPho 0.18um	3-16-27	1-14-28

MPW name	Fab	Processes	Tape-In	Ship Date
42nd MPW - Uozu, Japan	TPSCo - Fab 7	CMOS, PM, RFCMOS & SiGe, 65nm : TPS65SLA/SLC, TPS65PMA/PMB/PMC/PMD/PMK/PML/MSA/MSB/MSB/MSD/M SK/MSL, TPS65RF, TPS65SG	3-23-27	**
SBC18S6MPCA - B6705	NPB - Fab 3	SiGe BiCMOS 0.18um with PCM RF Switch	3-30-27	**
43rd MPW - Uozu, Japan	TPSCo - Fab 7	300mm Silicon Photonics: TPS45PHD	4-12-26	**
SB*18 - B6706	TSSA - Fab 9	SiGe BiCMOS 0.18um	4-13-27	**
CA18 - B6707	NPB - Fab 3	RFCMOS 0.18um	4-27-27	11-04-27
PH18M* - B6708	NPB - Fab 3	SiPho 0.18um	5-11-27	1-03-28
41st MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	5-24-27	**
SB*18 - B6709	NPB - Fab 3	SiGe BiCMOS 0.18um	5-25-27	12-13-27
SB*/CA13* - B6710	NPB - Fab 3	SiGe BiCMOS/RF CMOS 0.13um	6-08-27	2-08-28
PH18DA - B6711	NPB - Fab 3	SiPho 0.18um	6-22-27	4-21-28
SB*18 - B6712	NPB - Fab 3	SiGe BiCMOS 0.18um	7-13-27	1-31-28
CA18 - B6713	NPB - Fab 3	RFCMOS 0.18um	7-27-27	1-07-28
PH18M* - B6714	NPB - Fab 3	SiPho 0.18um	8-10-27	4-03-28
42nd MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	8-23-27	**
SB*18 - B6715	NPB - Fab 3	SiGe BiCMOS 0.18um	8-24-27	3-02-28
SBC18S6MPCA - B6716	NPB - Fab 3	SiGe BiCMOS 0.18um with PCM RF Switch	9-14-27	**
44th MPW - Uozu, Japan	TPSCo - Fab 7	CMOS, PM, RFCMOS & SiGe, 65nm : TPS65SLA/SLC, TPS65PMA/PMB/PMC/PMD/PMK/PML/MSA/MSB/MSB/MSD/M SK/MSL, TPS65RF, TPS65SG	9-27-27	**
SB*18 - B6717	NPB - Fab 3	SiGe BiCMOS 0.18um	10-05-27	4-13-28
45th MPW - Uozu, Japan	TPSCo - Fab 7	300mm Silicon Photonics: TPS45PHD	10-25-26	**
PH18M* - B6718	NPB - Fab 3	SiPho 0.18um	10-26-27	6-19-28
43rd MPW - Tonami, Japan	TPSCo - Fab 5	CMOS 0.18u & 0.16u, PM, PM_SOI	11-24-27	**

Notes: "Shuttles" (SH*) are run at Fab 2

* 0.13u MH – fab 2 Shuttle / MPW slots will be considered per needs

** Contact your Account Manager for details.

Please contact your customer account manager for additional information.

Fab2 - Tower Semiconductor 200mm wafer fabrication facility at Migdal Ha'emek, Israel

Fab3 - Tower Semiconductor 200mm wafer fabrication facility at Newport Beach, CA

Fab5 - Tower Semiconductor 200mm wafer fabrication facility at Tonami, Japan

Fab7 - Tower Semiconductor 300mm wafer fabrication facility at Uozu, Japan

Fab9 - Tower Semiconductor 200mm wafer fabrication facility at San Antonio, TX

Fab10 - Tower Semiconductor 300mm wafer fabrication facility at Agrate, Italy

Fab11 - Tower Semiconductor 300mm wafer fabrication facility at Rio Rancho, NM